

PMV20XNE 30 V, N-channel Trench MOSFET 10 November 2014

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Enhanced power dissipation capability of 1200 mW
- ElectroStatic Discharge (ESD) protection: 2 kV HBM

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	7.2	А
Static characteristics						_	
$R_{DSon} \qquad drain-source on-state resistance \qquad V_{GS} = 4.5 V; I_D = 5.7 A; T_j = 25 ^{\circ}C \qquad - 19 \qquad 23 \qquad m\Omega$							

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 2 TO-236AB (SOT23)	G G S S 017aaa255

6. Ordering information

Table 3. Ordering information				
Type number Package				
	Name	Description	Version	
PMV20XNE	TO-236AB	plastic surface-mounted package; 3 leads	SOT23	

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMV20XNE	%G9

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

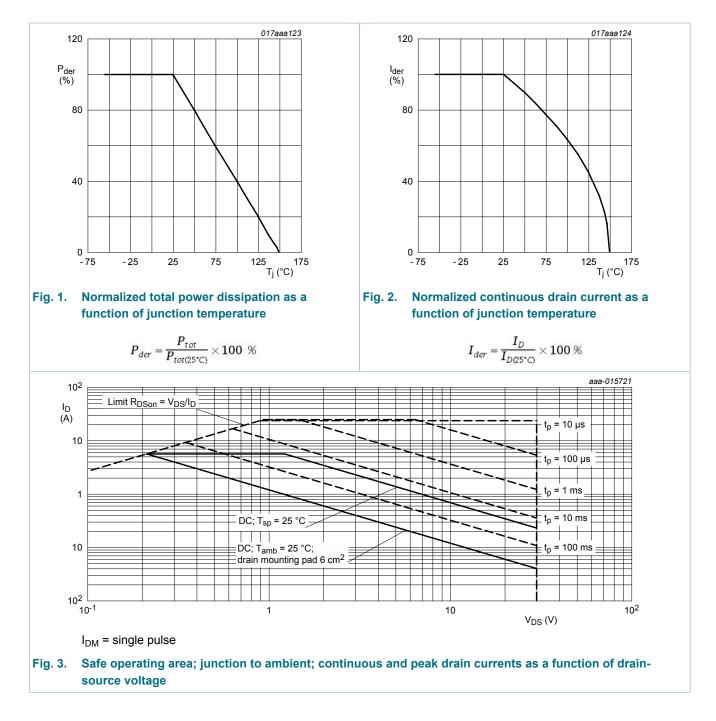
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V	
V _{GS}	gate-source voltage			-12	12	V	
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	7.2	А	
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	5.7	А	
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	3.6	А	
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	24	А	
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	510	mW	
			[1]	-	1200	mW	
		T _{sp} = 25 °C		-	6940	mW	
Tj	junction temperature			-55	150	°C	
T _{amb}	ambient temperature			-55	150	°C	
T _{stg}	storage temperature			-65	150	°C	
Source-dra	Source-drain diode						
I _S	source current	T _{amb} = 25 °C	[1]	-	1.2	А	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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9. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance	in free air	[1]	-	208	245	K/W	
from junction to ambient			[2]	-	88	104	K/W
		in free air; t ≤ 5 s	[2]	-	55	65	K/W

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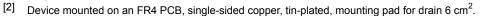
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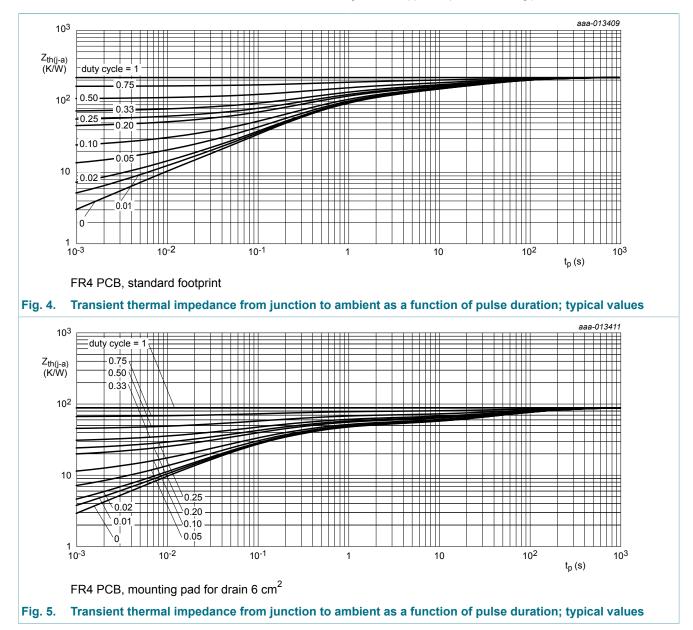
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point		-	13	18	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.





10. Characteristics

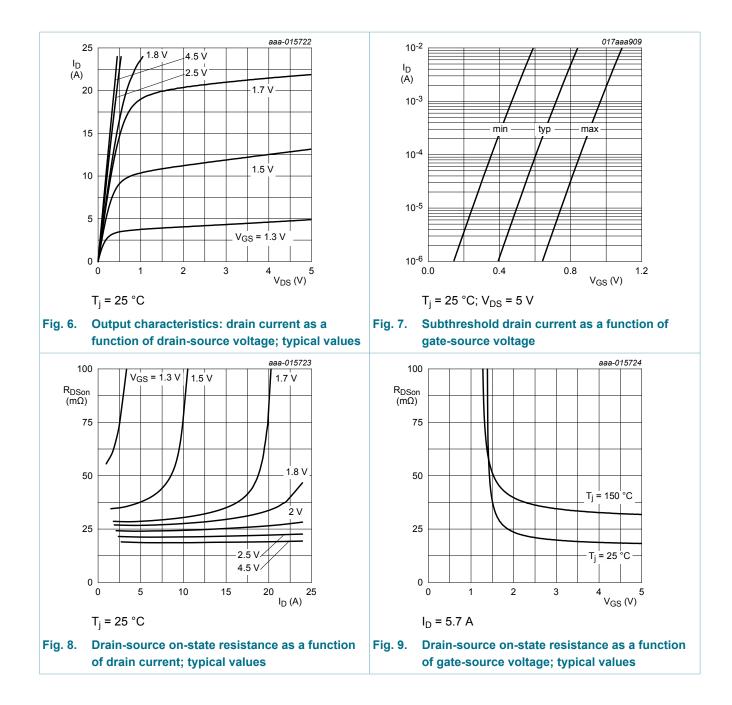
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	0.4	0.65	0.9	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
R _{DSon} drain-source on-state resistance	drain-source on-state	V_{GS} = 4.5 V; I _D = 5.7 A; T _j = 25 °C	-	19	23	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 5.7 A; T _j = 150 °C	-	31	37	mΩ
		V _{GS} = 2.5 V; I _D = 5 A; T _j = 25 °C	-	22	30	mΩ
	V _{GS} = 1.8 V; I _D = 1.9 A; T _j = 25 °C	-	27	38	mΩ	
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 2 A; T _j = 25 °C	-	11	-	S
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	-	1.8	-	Ω
Dynamic ch	aracteristics	1	I			
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 5 A; V _{GS} = 4.5 V;	-	12.4	18.6	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.2	-	nC
Q _{GD}	gate-drain charge		-	2.1	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V;	-	1150	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	110	-	pF
C _{rss}	reverse transfer capacitance		-	85	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; I _D = 5 A; V_{GS} = 4.5 V;	-	8	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	17	-	ns
t _{d(off)}	turn-off delay time		-	33	-	ns
t _f	fall time		-	32	-	ns
Source-drai	n diode	· · · · · · · · · · · · · · · · · · ·	1	1		
V _{SD}	source-drain voltage	I _S = 1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

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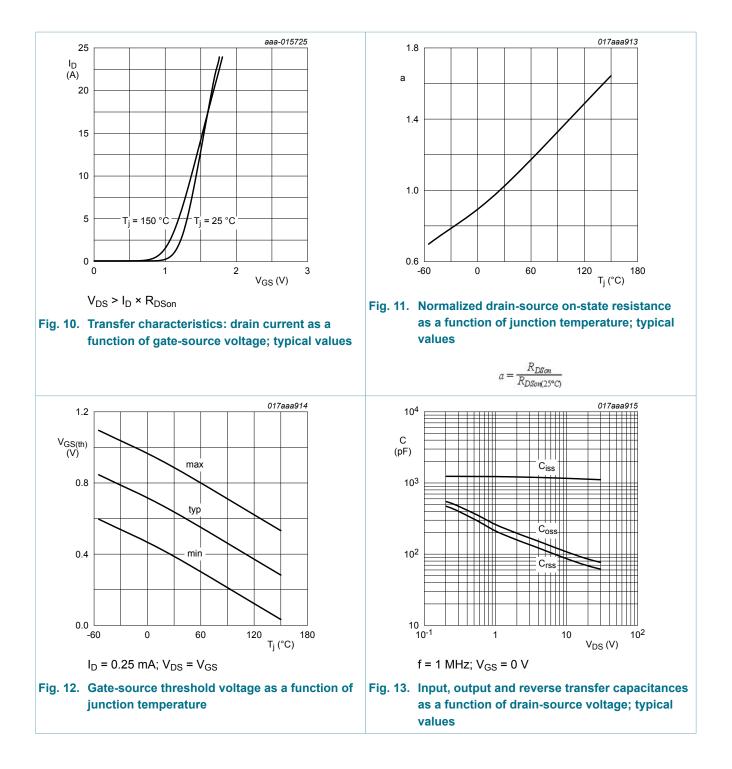
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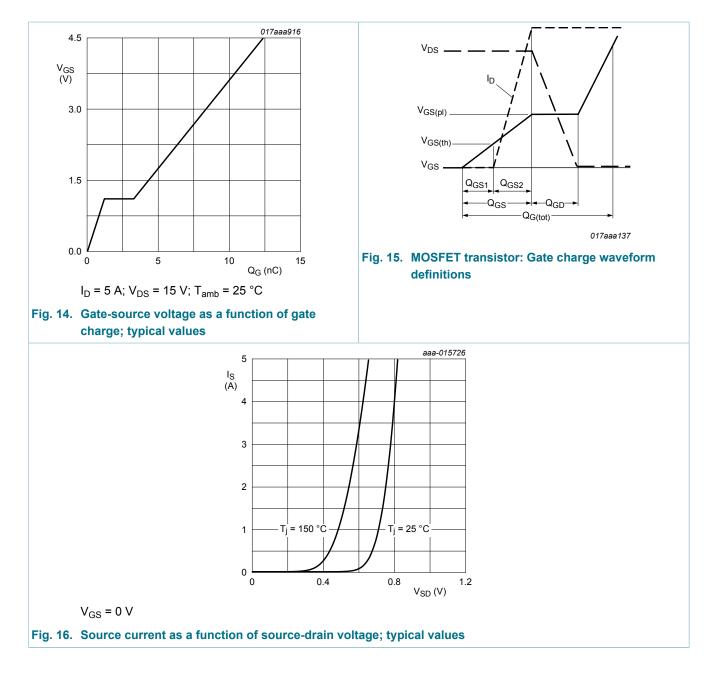
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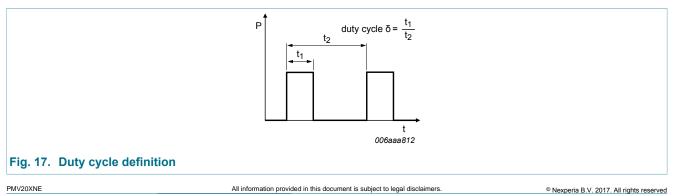
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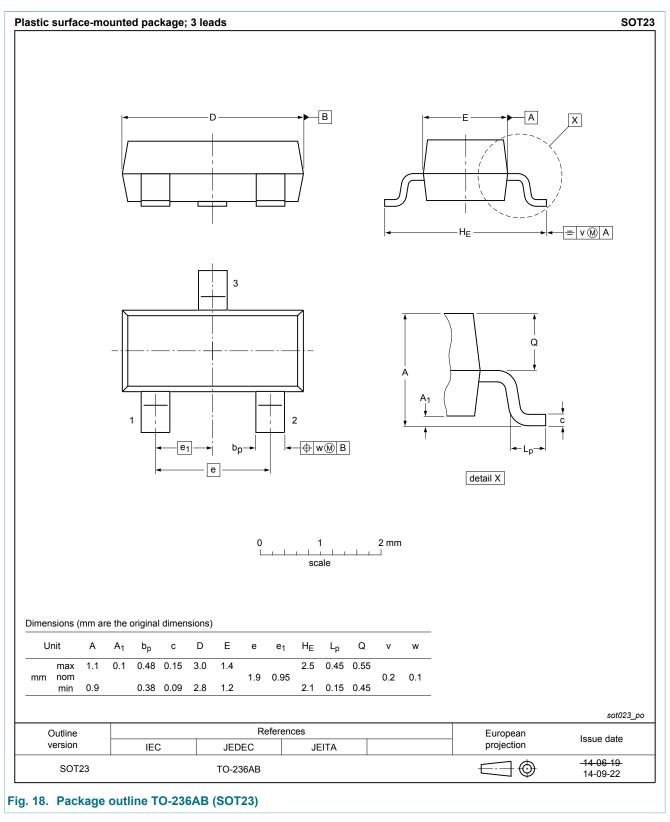
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11. Test information



12. Package outline

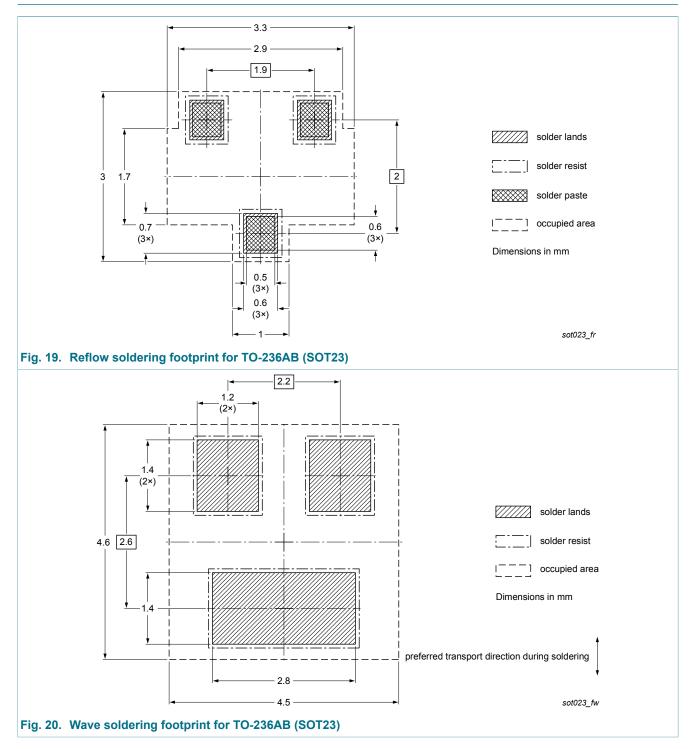


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13. Soldering



14. Revision history

Table 8. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMV20XNE v.1	20141110	Product data sheet	-	-

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15. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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